



40V COMPLEMENTARY SMALL-SIGNAL TRANSISTOR IN SOT363

Features

- Complementary Pair: One 3904-Type NPN
 One 3906-Type PNP
- Ultra-Small Surface-Mount Package
- Epitaxial Planar Die Construction
- Ideal for Low Power Amplification and Switching
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An automotive-compliant part is available under separate datasheet (MMDT3946Q)

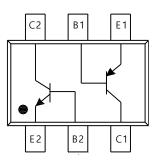
Mechanical Data

- Package: SOT363
- Package Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Finish. Solderable per MIL-STD-202, Method 208 <a>®3
- Weight: 0.006 grams (Approximate)



SOT363





E1, B1, C1 = PNP 3906 E2, B2, C2 = NPN 3904

Device Schematic and Pinout Top View

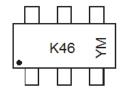
Ordering Information (Note 4)

Orderable Part Number	Dookogo	Marking	Reel Size (inches)	Tape Width (mm)	Pac	king
Orderable Fait Number	Package	Warking	Reel Size (Illulies)	rape widin (min)	Qty	Carrier
MMDT3946-7-F	SOT363	K46	7	8	3,000	Reel
MMDT3946-7R-F	SOT363	K46	7	8	3,000	Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



K46 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: M = 2025) M = Month (ex: 9 = September)

Date Code Key

Year	2003	-	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034
Code	Р	-	М	Ν	Р	R	S	Т	J	V	W	X
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings, NPN 3904 (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	60	V
Collector-Emitter Voltage	$V_{\sf CEO}$	40	V
Emitter-Base Voltage	VEBO	6	V
Collector Current	Ic	200	mA

Absolute Maximum Ratings, PNP 3906 (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	-40	V
Collector-Emitter Voltage	$V_{\sf CEO}$	-40	V
Emitter-Base Voltage	VEBO	-5	V
Collector Current	Ic	-200	mA

Thermal Characteristics, Total Device (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{ hetaJA}$	625	°C/W
Operating and Storage Temperature Range	TJ, Tsтg	-55 to +150	°C

Note: 5. For a device mounted on minimum recommended pad layout that is on a single-sided 0.6mm FR-4 PCB; device is measured under still air conditions while operating in a steady state.

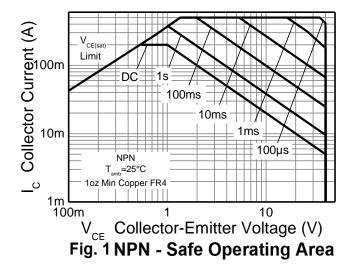
ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С
Electrostatic Discharge - Charged Device Model	ESD CDM	1,000	V	C3

Note: 6. Refer to JEDEC specification JESD22-A114, JESD22-A115 and JESD22-C101.



Thermal Characteristics and Derating Information



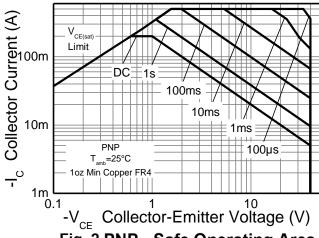
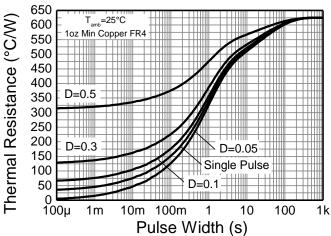


Fig. 2 PNP - Safe Operating Area



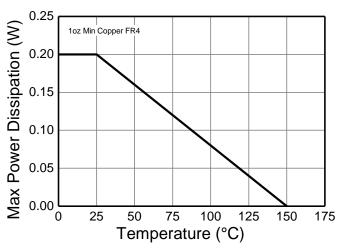


Fig. 3 Transient Thermal Impedance

Fig. 4 Derating Curve

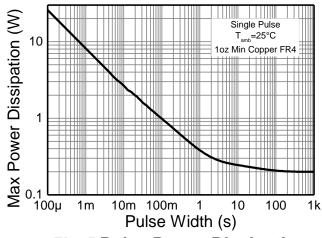


Fig. 5 Pulse Power Dissipation



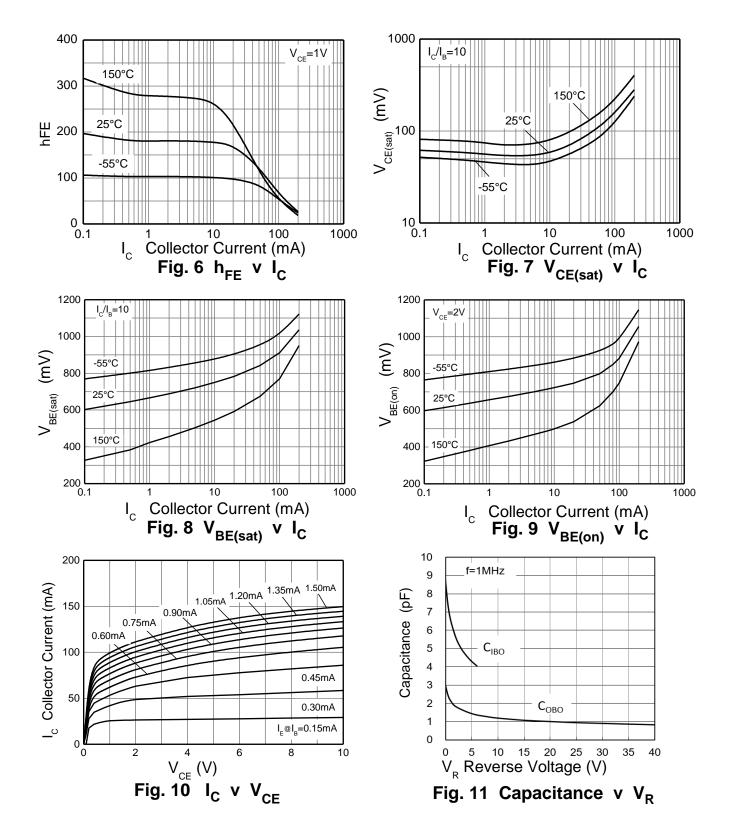
Electrical Characteristics, NPN 3904 (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)					
Collector-Base Breakdown Voltage	BV _{CBO}	60	_	V	$I_C = 10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	BV _{CEO}	40	_	V	$I_C = 1mA, I_B = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	6	_	V	$IE = 10\mu A, IC = 0$
Collector Cutoff Current	ICEX		50	nA	VCE = 30V, VEB(OFF) = 3V
Base Cutoff Current	I _{BL}	_	50	nA	VCE = 30V, VEB(OFF) = 3V
ON CHARACTERISTICS (Note 7)	_				
Static Forward Current Transfer Ratio	hFE	40 70 100 60 30	300 — —	_	$I_{C} = 100\mu A, V_{CE} = 1V$ $I_{C} = 1mA, V_{CE} = 1V$ $I_{C} = 10mA, V_{CE} = 1V$ $I_{C} = 50mA, V_{CE} = 1V$ $I_{C} = 100mA, V_{CE} = 1V$
Collector-Emitter Saturation Voltage	V _{CE(sat)}		0.20 0.30	V	$I_C = 10$ mA, $I_B = 1$ mA $I_C = 50$ mA, $I_B = 5$ mA
Base-Emitter Saturation Voltage	V _{BE(sat)}	0.65	0.85 0.95	V	I _C = 10mA, I _B = 1mA I _C = 50mA, I _B = 5mA
SMALL-SIGNAL CHARACTERISTICS					
Output Capacitance	C _{obo}	_	4.0	pF	$V_{CB} = 5V$, $f = 1MHz$, $I_E = 0$
Input Capacitance	Cibo		8.0	pF	$V_{EB} = 0.5V$, $f = 1MHz$, $I_{C} = 0$
Input Impedance	hie	1	10	kΩ	
Voltage Feedback Ratio	hre	0.5	8	x 10 ⁻⁴	Vce = 10V, Ic = 1mA,
Small-Signal Current Gain	h _{fe}	100	400	_	f = 1kHz
Output Admittance	hoe	1	40	μS	
Current Gain-Bandwidth Product	f⊤	300	_	MHz	V _{CE} = 20V, I _C = 20mA, f = 100MHz
Noise Figure	NF	_	5	dB	V_{CE} = 5V, Ic = 100μA, Rs = 1kΩ, f = 1kHz
SWITCHING CHARACTERISTICS					
Delay Time	td		35	ns	Vcc = 3V, Ic = 10mA,
Rise Time	tr		35	ns	$V_{BE(off)} = 0.5V$, $I_{B1} = 1mA$
Storage Time	ts		200	ns	Vcc = 3V, Ic = 10mA,
Fall Time	t _f		50	ns	$I_{B1} = -I_{B2} = 1mA$

Note: 7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics, NPN 3904 (@TA = +25°C, unless otherwise specified.)





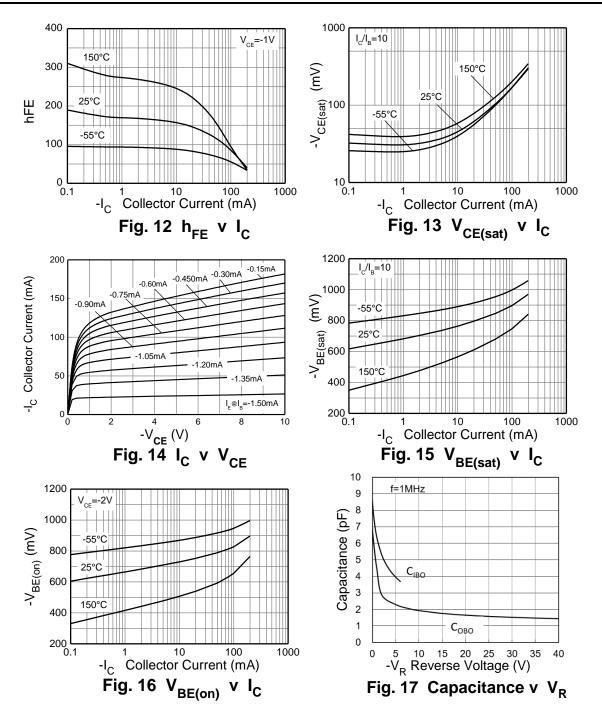
Electrical Characteristics, PNP 3906 (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	•				
Collector-Base Breakdown Voltage	ВУсво	-40	_	V	$I_C = -10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	BV _{CEO}	-40		V	$I_C = -1mA, I_B = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	_	V	$I_E = -10\mu A, I_C = 0$
Collector Cutoff Current	ICEX		-50	nA	VCE = -30V, $VEB(OFF) = -3V$
Base Cutoff Current	IBL		-50	nA	VCE = -30V, $VEB(OFF) = -3V$
ON CHARACTERISTICS (Note 7)					
Static Forward Current Transfer Ratio	hFE	60 80 100 60 30	300 — —	_	$\begin{split} I_C &= -100 \mu A, \ V_{CE} = -1 V \\ I_C &= -1.0 m A, \ V_{CE} = -1 V \\ I_C &= -10 m A, \ V_{CE} = -1 V \\ I_C &= -50 m A, \ V_{CE} = -1 V \\ I_C &= -100 m A, \ V_{CE} = -1 V \end{split}$
Collector-Emitter Saturation Voltage	VCE(sat)		-0.25 -0.40	V	$I_C = -10$ mA, $I_B = -1$ mA $I_C = -50$ mA, $I_B = -5$ mA
Base-Emitter Saturation Voltage	V _{BE} (sat)	-0.65 —	-0.85 -0.95	V	$I_C = -10mA$, $I_B = -1mA$ $I_C = -50mA$, $I_B = -5mA$
SMALL-SIGNAL CHARACTERISTICS					
Output Capacitance	C _{obo}		4.5	pF	$V_{CB} = -5.0V$, $f = 1MHz$, $I_E = 0$
Input Capacitance	Cibo		10	pF	$V_{EB} = -0.5V, f = 1MHz, I_{C} = 0$
Input Impedance	h _{ie}	2.0	12	kΩ	
Voltage Feedback Ratio	h _{re}	0.1	10	x 10 ⁻⁴	Vce = -10V, Ic = -1mA,
Small-Signal Current Gain	h _{fe}	100	400	_	f = 1kHz
Output Admittance	h _{oe}	3	60	μS	
Current Gain-Bandwidth Product	fτ	250	_	MHz	V _{CE} = -20V, I _C = -10mA, f = 100MHz
Noise Figure	NF	_	4	dB	V_{CE} = -5V, I_C = -100 μ A, R_S = 1k Ω , f = 1kHz
SWITCHING CHARACTERISTICS					
Delay Time	td	_	35	ns	Vcc = -3V, Ic = -10mA,
Rise Time	tr	_	35	ns	$V_{BE(off)} = -0.5V$, $I_{B1} = -1mA$
Storage Time	ts		225	ns	$V_{CC} = -3V, I_{C} = -10mA,$
Fall Time	t _f	_	75	ns	$I_{B1} = -I_{B2} = -1mA$

Note: 7. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



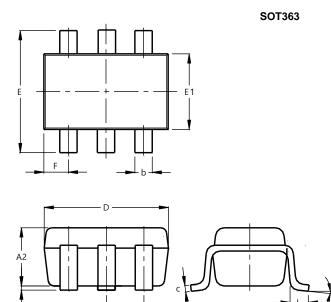
Typical Electrical Characteristics, PNP 3906 (@TA = +25°C, unless otherwise specified.)





Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

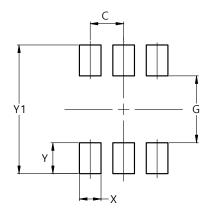


SOT363						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.90	1.00	0.95			
b	0.10	0.30	0.25			
С	0.10	0.22	0.11			
D	1.80	2.20	2.15			
Е	2.00	2.20	2.10			
E1	1.15	1.35	1.30			
е	0.650 BSC					
F	0.40	0.45	0.425			
L	0.25	0.40	0.30			
а	0°	8°				
All l	Dimen	sions	in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT363



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.420
Υ	0.600
V1	2 500



IMPORTANT NOTICE

- 1. DIODES INCORPORATED (Diodes) AND ITS SUBSIDIARIES MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).
- 2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes' products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes' products. Diodes' products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of Diodes' products for their intended applications, (c) ensuring their applications, which incorporate Diodes' products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.
- 3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.
- 4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.
- provided Diodes' products are subject to Diodes' Standard and Conditions of Sale Terms (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.
- 6. Diodes' products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes' products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.
- 7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.
- 8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.
- 9. This Notice may be periodically updated with the most recent version available at https://www.diodes.com/about/company/terms-and-conditions/important-notice

The Diodes logo is a registered trademark of Diodes Incorporated in the United States and other countries. All other trademarks are the property of their respective owners.

© 2025 Diodes Incorporated. All Rights Reserved.

www.diodes.com